



## SDHCAL digitisation

### Calice Collaboration Meeting - Argonne

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IPNL

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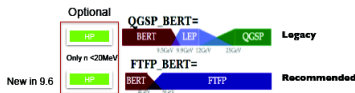


# Outline

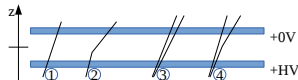
- 1 SDHCAL digitizer
- 2 Mips study
- 3 Data time calibration
- 4 Electromagnetic shower
- 5 Hadronic shower
- 6 Conclusion and plans

# Simulation/Digitizer method

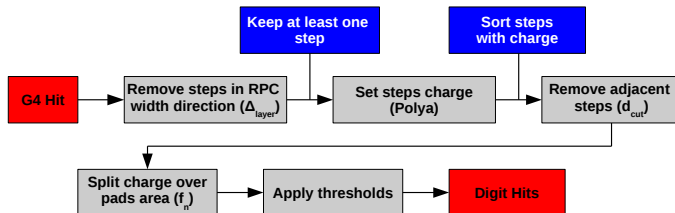
Simulation :



- Geant4 version 9.6.p01 is used
- FTFP\_BERT\_HP is used

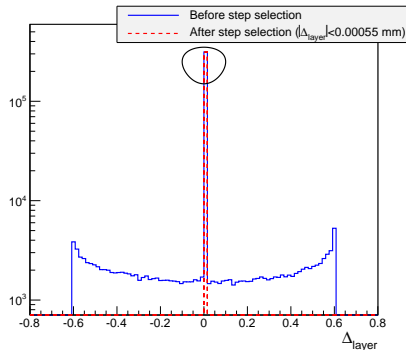
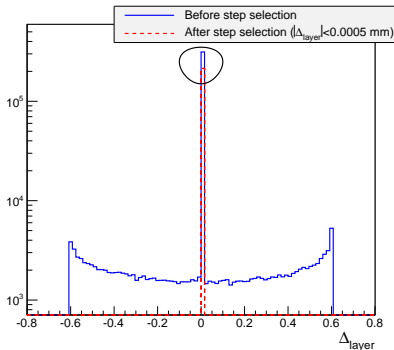


Digitizer :



# Bug correction

- $\Delta_{layer} = stepMidPosition - rpcMidPosition$
- Difference between simulation program parameters and gear file used for digitization induces a shift for  $\Delta_{layer}$



# Digitizer functions

- Polya function to simulate induced charge from charged particles :

$$P(q) = \left(q \frac{1+\theta}{\bar{q}}\right) e^{-\frac{q}{\bar{q}}(1+\theta)} \quad (1)$$

- Charge splitting function :

$$f_n(x, y) = \sum_{i=0}^n \alpha_i e^{-\frac{(x_0-x)^2+(y_0-y)^2}{\sigma_i^2}} \quad (2)$$

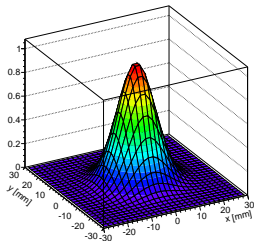
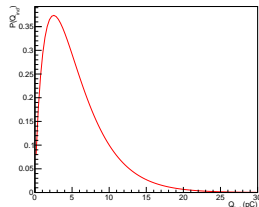
with  $\alpha_0 > \alpha_1 > \dots > \alpha_n$  and  $\sigma_0 < \sigma_1 < \dots < \sigma_n$

- Speed up integration over pads area using the error function  $Erf(x)$ , tabulated in C++ libraries (factor >10) :

$$\int_a^b e^{-\frac{x^2}{\sigma^2}} dx = \frac{\sqrt{\pi}\sigma}{2} \left( Erf\left(\frac{b}{\sigma}\right) - Erf\left(\frac{a}{\sigma}\right) \right) \quad (3)$$

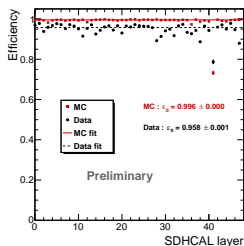
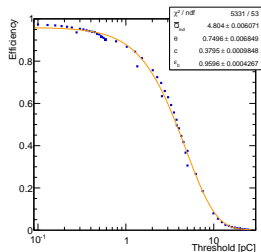
where

$$Erf(x) = \frac{2}{\sqrt{\pi}} \int_0^x e^{-t^2} dt \quad (4)$$



# Mips study

- Hits in prototype dead cells (<1%) removed in simulation before the analysis
- Polya parameters extracted from a threshold scan study
- First Threshold value : 0.114 pC
- Mips selection :
  - $\frac{N_{hit}}{N_{layer}} < 3$
  - $N_{layer} > 30$
  - $\frac{\sqrt{\lambda_1^2 + \lambda_2^2}}{\lambda_3} < 0.02$ ; with  $\lambda_{1,2,3}$  three eigen values of a PCA ( $\lambda_1 < \lambda_2 < \lambda_3$ )



# Mips study

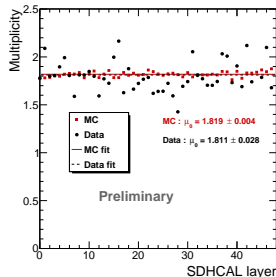
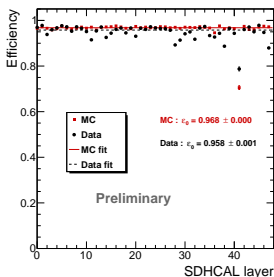
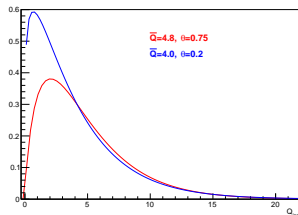
Need to introduce inefficiency in simulation :

- Change Polya parameters :  $\bar{Q} = 4.0 pC$ ;  
 $\theta = 0.2$
- Threshold 1 : 0.160 pC

Charge splitting function parameters ( $f_2$ ):

Parameter	Value
$\alpha_0$	1
$\sigma_0$	1 mm
$\alpha_1$	0.0019
$\sigma_1$	9.2 mm

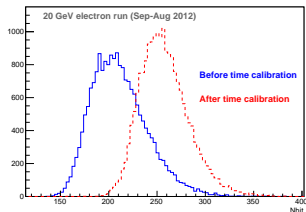
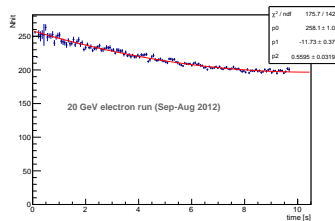
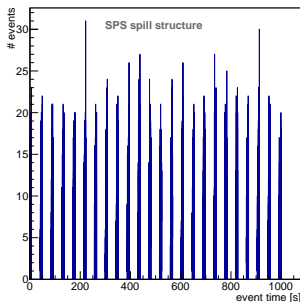
Polya distributions



# Data time calibration

- Time to absorb the charge in the glass
- Event time in the spill ( $\simeq 10$  s at SPS) is reconstructed
- One calibration per run per threshold

$$N_{corrected} = N_{hit} - (p_2 SpillTime^2 + p_1 SpillTime) \quad (5)$$





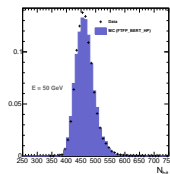
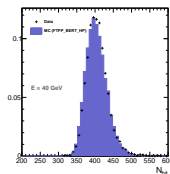
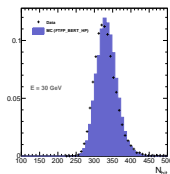
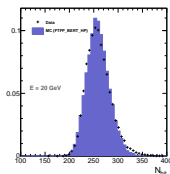
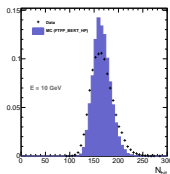
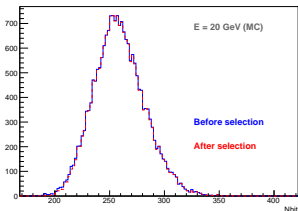
# Electromagnetic shower

- $d_{cut} = 0.5 \text{ mm}$

- Electron selection :

- $N_{hit}/N_{layer} > 3$
  - $\frac{N_{Int\ layer}}{N_{layer}} > 20\%$
  - $0 \leq Z_{begin} < 5$
  - $N_{layer} < 30$
  - $V_1 V_2 > cut(E_{beam})$  with
- $$V_1 = \frac{N_{hit}^{25}}{N_{hit}} \text{ ans } V_2 = \frac{FD_{3D}}{\ln N_{hit}}$$

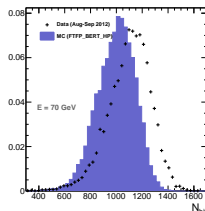
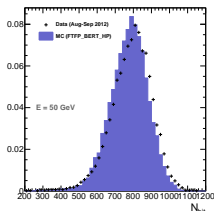
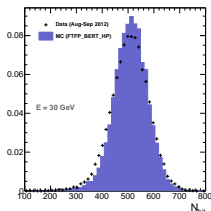
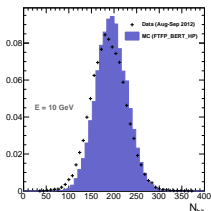
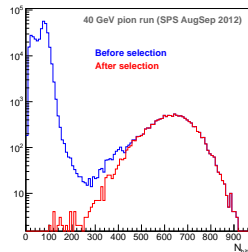
$E_{beam} [\text{GeV}]$	cut
10	0.18
20	0.17
30	0.16
40	0.15
50	0.13



# Hadronic shower

- Thresholds :  
0.160, 3.9, 11.0  $pC$
- Pion selection :
  - $\frac{N_{hit}}{N_{layer}} > 3$
  - $SSL \geq 0$
  - $\frac{N_{Int\ layer}}{N_{layer}} > 20\%$
  - $V_1 \cdot V_2 < cut(E_{beam})$

$E_{beam}$ [GeV]	cut
5	0.20
10 – 15	0.18
20 – 25	0.17
30	0.16
40	0.15
50 – 70	0.13
80	0.12

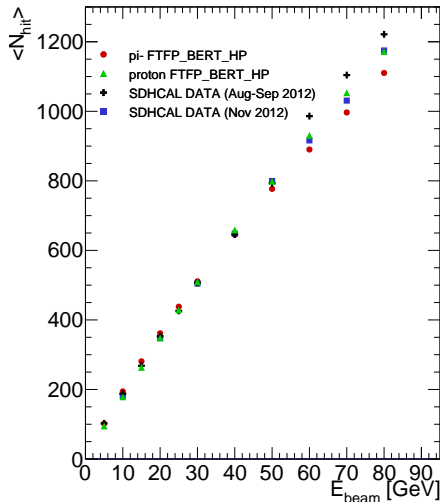
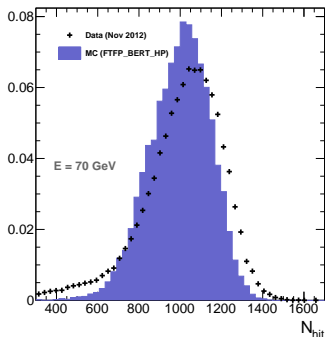


# Hadronic shower

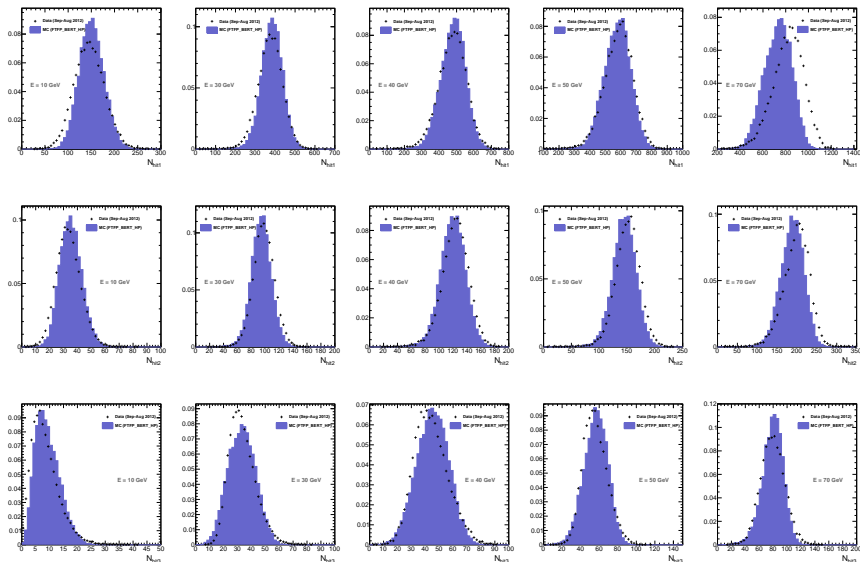
- Proton contamination in H6 beam line above 20 GeV [*NIM A 621 (2010) 134-150*].

Energy [GeV]	Fraction of protons
50	$0.45 \pm 0.12$
100	$0.61 \pm 0.06$

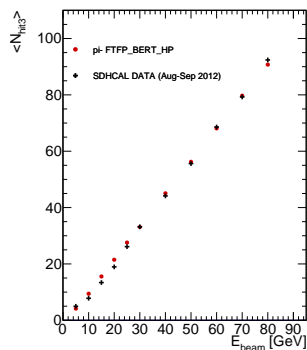
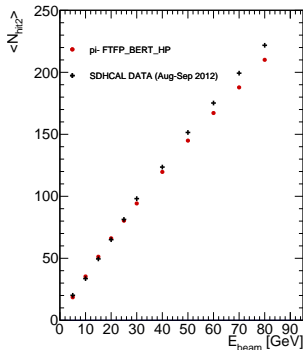
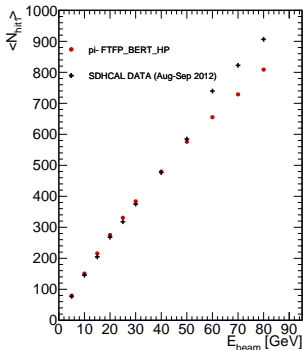
- November 2012 data in H2 beam line



# Hadronic shower



# Hadronic shower



## Conclusion :

- Bug corrections have been done
- Erf option is available in ILC Soft version v01-17-05 (MarlinReco v01-08-01)
- Digitizer parameters tuned with electrons and with muons :
  - Polya and charge splitting functions tuned with muons.
  - $d_{cut}$  tuned with electrons.
  - Only thresholds 2 and 3 tuned with pions.
- Good agreement between data and simulation found for muons and electrons (total number of hits).
- Good agreement between data and simulation found for pions until 50 GeV.

## Plans :

- Study hadronic shower models.
  - Energy resolution
  - Shower topology : profile, density, track segments
- Full ILD simulation study :
  - ILD optimization : HCAL radius, cell size